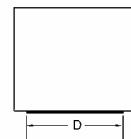
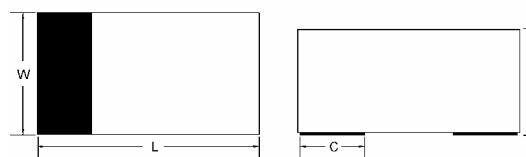
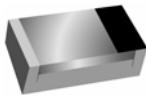




# TSS40L

## 0.2Amp Surface Mount Schottky Barrier Diode

1005



### Features

- ✧ Designed for mounting on small surface
- ✧ Extremely thin/leadless package
- ✧ Low capacitance
- ✧ Low forward voltage drop
- ✧ High temperature soldering:  
260°C/10 seconds at terminals
- ✧ Chip version in 1005

### Mechanical Data

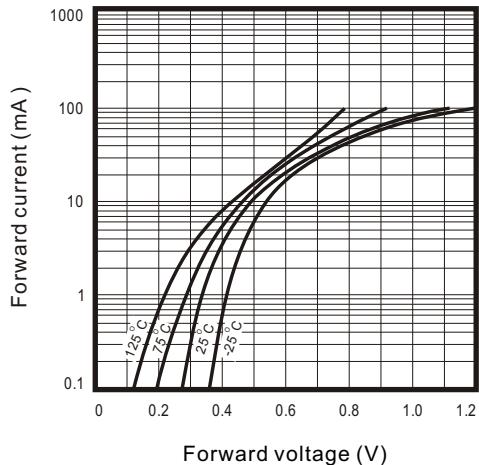
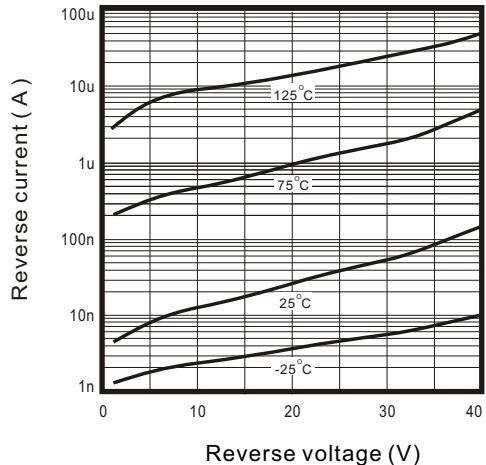
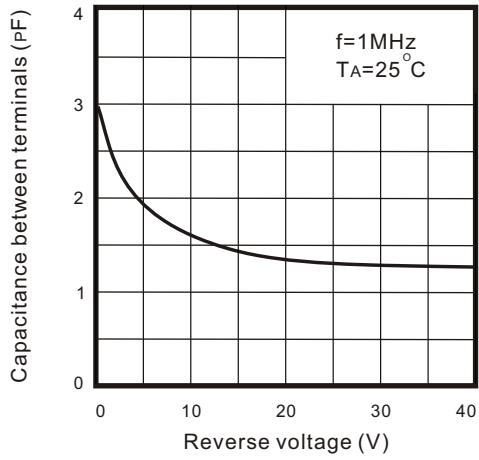
- ✧ Case: 1005 Standard package, molded plastic
- ✧ Terminals: Gold plated, solderable per  
MIL-STD-750, method 2026.
- ✧ Polarity: Indicated by cathode band
- ✧ Mounting position: Any
- ✧ Package code: RW
- ✧ Weight: 0.006 gram (approximately)

| ITEM | 1005                       |
|------|----------------------------|
| L    | 0.102(2.60)<br>0.095(2.40) |
| W    | 0.051(1.30)<br>0.043(1.10) |
| T    | 0.035(0.90)<br>0.027(0.70) |
| C    | 0.020(0.50)<br>Typical     |
| D    | 0.040(1.00)<br>Typical     |

Dimensions in inches and (millimeters)

Maximum Ratings  $T_A=25^\circ\text{C}$  unless otherwise specified

| Type Number   | Symbol       | 1005         | Units |
|---|--------------|--------------|-------|
| Repetitive Peak Reverse Voltage   | $V_{RRM}$    | 40           | V     |
| Reverse Voltage   | $V_R$        | 40           | V     |
| RMS Reverse Voltage   | $V_{R(RMS)}$ | 28           | V     |
| Average Forward Current   | $I_O$        | 200          | mA    |
| Peak Forward Surge Current<br>8.3ms single half sine-wave superimposed on<br>rate load (JEDEC method) | $I_{FSM}$    | 600          | mA    |
| Power Dissipation   | $P_d$        | 200          | mW    |
| Forward Voltage $IF=1.0\text{mA}$<br>$IF=40\text{mA}$   | $V_F$        | 0.38<br>1.0  | V     |
| Reverse Leakage Current $VR=30V$  | $I_R$        | 0.2          | uA    |
| Typical capacitance between terminals<br>$VR=0V$ , $f =1.0\text{MHz}$ reverse voltage                 | $C_J$        | 3            | pF    |
| Reverse Recovery Time<br>( $IF=IR=10\text{mA}$ , $Irr=0.1 \times IR$ , $RL=100\Omega$ )               | $T_{rr}$     | 5            | nS    |
| Junction Temperature  | $T_J$        | -65 to + 125 | °C    |
| Storage Temperature   | $T_{STG}$    | -65 to + 125 | °C    |

**RATINGS AND CHARACTERISTIC CURVES(TSS40L)**
**Fig. 1 - Forward characteristics**

**Fig. 2 - Reverse characteristics**

**Fig.3 - Capacitance between terminals characteristics**

**Fig.4 - Current derating curve**
